



SMBJSAC5.0 thru SMBJSAC75, e3

500 WATT LOW CAPACITANCE TRANSIENT VOLTAGE SUPPRESSOR

DESCRIPTION

The SMBJSAC transient voltage suppressor (TVS) series rated at 500 Watts provides an added rectifier element as shown in Figure 4 to achieve low capacitance in applications for data or signal lines. The low capacitance rating of less than 30 pF may be used for protecting higher frequency applications in inductive switching environments or electrical systems involving secondary lightning effects per IEC61000-4-5 as well as RTCA/DO-160D or ARINC 429 for airborne avionics. If bidirectional protection is needed, two SMBJSAC devices in anti-parallel configuration are required as shown in Figure 6. With their very fast response time, they also provide ESD and EFT protection per IEC61000-4-2 and IEC61000-4-4 respectively.

APPEARANCE



DO-214AA
See package notes

IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

FEATURES

- Unidirectional low-capacitance TVS series (for bidirectional see Figure 6)
- Suppresses transient up to 500 Watts Peak Pulse Power @ 10/1000 μ s
- Improved performance in low capacitance of 30 pF
- Economical small plastic surface mount with robust axial subassembly package
- Optional 100% **screening for avionics grade** is available by adding MA prefix to part number for added 100% temperature cycle -55°C to +125°C (10X) as well as surge (3X) and 24 hours HTRB with post test V_Z & I_R
- Options for screening in accordance with MIL-PRF-19500 for JAN, JANTX, and JANTXV are also available by adding MQ, MX, or MV prefixes respectively to part number, e.g. MXSMBJSAC5.0, MVSMBJSAC18, etc.
- Moisture classification is Level 1 with no dry pack required per IPC/JEDEC J-STD-020B
- Also available in axial-leaded packages with part numbers (SAC5.0 thru SAC50)
- RoHS Compliant devices available by adding "e3" suffix

APPLICATIONS / BENEFITS

- Low Capacitance for data-line protection to 10 MHz
- Protection for aircraft fast data rate lines per select waveforms in RTCA/DO-160D (see MicroNote 130 for Waveform 4 and 5A capability) & ARINC 429 with bit rates of 100 kb/s (per ARINC 429, Part 1, par. 2.4.1.1)
- ESD and EFT protection per IEC61000-4-2 and IEC61000-4-4 respectively
- Secondary lightning protection per IEC61000-4-5 with 42 Ohms source impedance:
 - Class 1: SMBJSAC5.0 to SMBJSAC75
 - Class 2: SMBJSAC5.0 to SMBJSAC45
 - Class 3: SMBJSAC5.0 to SMBJSAC22
 - Class 4: SMBJSAC5.0 to SMBJSAC10
- Secondary lightning protection per IEC61000-4-5 with 12 Ohms source impedance
 - Class 1: SMBJSAC5.0 to SMBJSAC26
 - Class 2: SMBJSAC5.0 to SMBJSAC15
 - Class 3: SMBJSAC5.0 to SMBJSAC7.0

MAXIMUM RATINGS

- Peak Pulse Power Dissipation at 25°C: 500 Watts @ 10/1000 μ s with repetition rate of 0.01% or less*
- Steady State Power Dissipation*: 2.5 Watts @ $T_L = +75^\circ\text{C}$
- Clamping Speed (0 volts to $V_{(BR)}$ Min.) less than 5 nanoseconds.
- Operating and Storage Temperature: -65°C to +150°C
- Solder temperatures: 260°C for 10 s maximum

MECHANICAL AND PACKAGING

- CASE: Void Free Transfer Molded Thermosetting Plastic package meeting UL94V-0
- FINISH: Tin-Lead or RoHS Compliant matte-Tin plating solderable per MIL-STD-750, method 2026
- POLARITY: Cathode (TVS) Marked with Band
- MARKING: Part number without SMBJ prefix (ie. SAC5.0, SAC5.0e3, etc)
- WEIGHT: 0.1 Grams (Approx.)
- See package dimensions on last page

* TVS devices are not typically used for dc power dissipation and are instead operated $\leq V_{WM}$ (rated standoff voltage) except for transients that briefly drive the device into avalanche breakdown (V_{BR} to V_C region) of the TVS element. Also see Figures 5 and 6 for further protection details in rated peak pulse power for unidirectional and bidirectional configurations respectively.



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ELECTRICAL CHARACTERISTICS @ 25°C

MICROSEMI PART NUMBER	REVERSE STAND-OFF VOLTAGE (Note 1) V_{WM} Volts	BREAKDOWN VOLTAGE @ $I_{(BR)} 1.0mA$ $V_{(BR)}$ Volts Min.	MAXIMUM STANDBY CURRENT @ V_{WM} I_D μA	MAXIMUM CLAMPING VOLTAGE $I_P = 5.0A^*$ V_C Volts	MAXIMUM PEAK PULSE CURRENT* RATING I_{PP} Amps	MAXIMUM CAPACITANCE @ 0 Volts, $f=1$ MHz pF	WORKING INVERSE BLOCKING VOLTAGE V_{WIB} Volts	INVERSE BLOCKING LEAKAGE CURRENT I_{IB} @ V_{WIB} μA	PEAK INVERSE BLOCKING VOLTAGE V_{PIB} Volts
SMBJSAC5.0	5.0	7.60	300	10.0	44	30	75	10	100
SMBJSAC6.0	6.0	7.90	300	11.2	41	30	75	10	100
SMBJSAC7.0	7.0	8.33	300	12.6	38	30	75	10	100
SMBJSAC8.0	8.0	8.89	100	13.4	36	30	75	10	100
SMBJSAC8.5	8.5	9.44	50	14.0	34	30	75	10	100
SMBJSAC10	10	11.10	5.0	16.3	29	30	75	10	100
SMBJSAC12	12	13.30	5.0	19.0	25	30	75	10	100
SMBJSAC15	15	16.70	5.0	23.6	20	30	75	10	100
SMBJSAC18	18	20.00	5.0	28.8	15	30	75	10	100
SMBJSAC22	22	24.40	5.0	35.4	14	30	75	10	100
SMBJSAC26	26	28.90	5.0	42.3	11.1	30	75	10	100
SMBJSAC36	36	40.0	5.0	60.0	8.6	30	75	10	100
SMBJSAC45	45	50.00	5.0	77.0	6.8	30	150	10	200
SMBJSAC50	50	55.50	5.0	88.0	5.8	30	150	10	200
SMBJSAC75	75	83.3	5.0	121	4.1	30	150	10	200

*See Figure 3. For the SMBJSAC75, the maximum clamping voltage V_C is at the maximum rated Peak Pulse Current (I_{PP}) of 4.1 Amps.

Clamping Factor: The ratio of the numerical value of V_C to $V_{(BR)}$ is typically 1.4 @ full rated power, 1.20 @ 50% rated power. Also see MicroNote 108.

Note 1: A transient voltage suppressor is normally selected according to voltage (V_{WM}), that should be equal to or greater than the dc or continuous peak operating voltage level.

Note 2: When pulse testing, test in TVS avalanche direction. Do not pulse in "forward" direction. See section for "Schematic Applications" herein.

GRAPHS

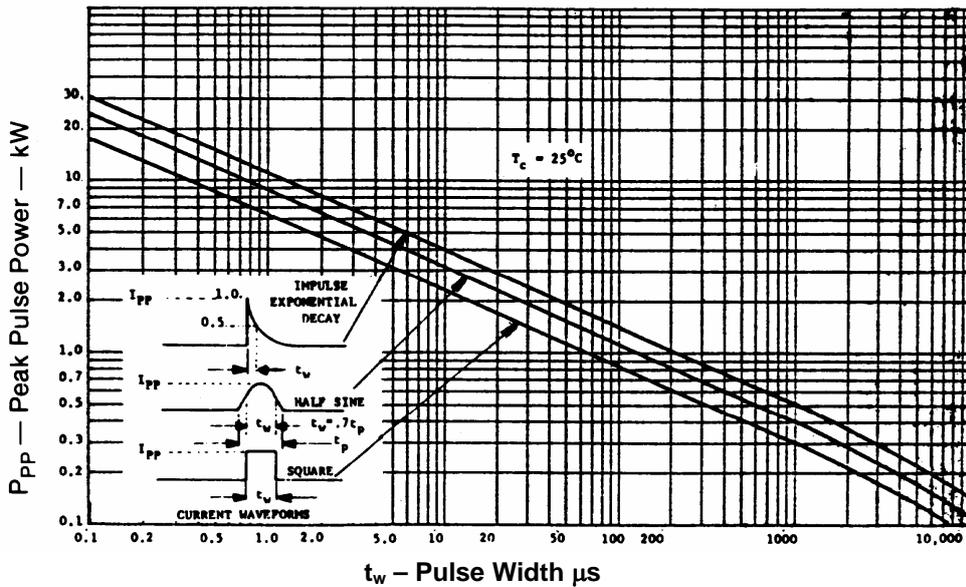
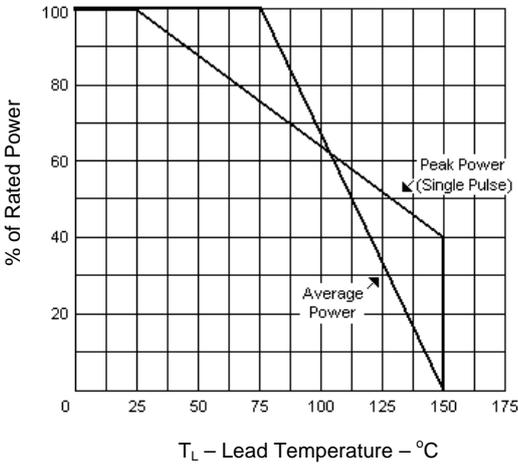


FIGURE 1



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T_L – Lead Temperature – °C
FIGURE 2
 Lead Length = 3/8"

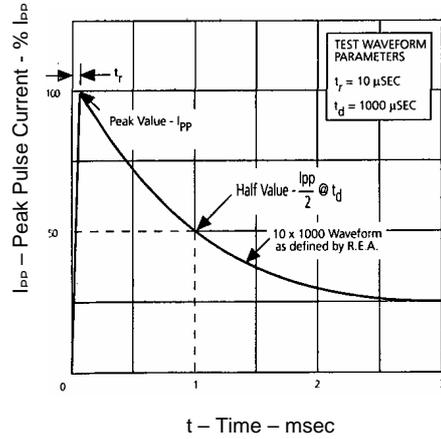


FIGURE 3

SCHEMATIC APPLICATIONS

The TVS low capacitance device configuration is shown in Figure 4. As a further option for unidirectional applications, an additional low capacitance rectifier diode may be used in parallel in the same polarity direction as the TVS as shown in Figure 5. In applications where random high voltage transients occur, this will prevent reverse transients from damaging the internal low capacitance rectifier diode and also provide a low voltage conducting direction. The added rectifier diode should be of similar low capacitance and also have a higher reverse voltage rating than the TVS clamping voltage V_C . The Microsemi recommended rectifier part number is the "SMBJLCR60" for the application in Figure 5. If using two (2) low capacitance TVS devices in anti-parallel for bidirectional applications, this added protective feature for both directions (including the reverse of each rectifier diode) is inherently provided in Figure 6. The unidirectional and bidirectional configurations in Figure 5 and 6 will both result in twice the capacitance of Figure 4.

SCHEMATIC

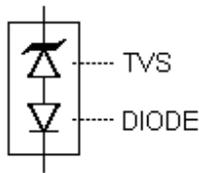


FIGURE 4
 TVS with internal Low Capacitance Diode

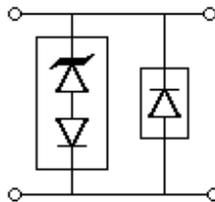


FIGURE 5
 Optional Unidirectional configuration (TVS and separate rectifier diode in parallel)

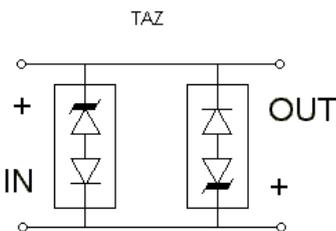


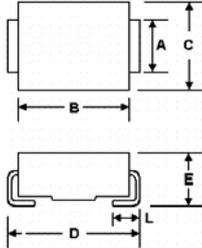
FIGURE 6 Optional Bidirectional configuration (two TVS devices in anti-parallel)



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PACKAGE DIMENSIONS & PAD LAYOUT



SMBJ

	A	B	C	D	E
MIN	.077	.160	.130	.205	.077
MAX	.083	.180	.155	.220	.104
DIMENSIONS IN MILLIMETERS					
MIN	1.96	4.06	3.30	5.21	1.95
MAX	2.10	4.57	3.94	5.59	2.65

